

Product Summary

B120Q/BQ-B140Q/BQ

V_{RRM} (V)	I_O (A)	V_F Max (V) $T_A = +25^\circ\text{C}$	I_R Max (mA) $T_A = +25^\circ\text{C}$
20/30/40	1.0	0.5	0.5

B150Q/BQ, B160Q/BQ

V_{RRM} (V)	I_O (A)	V_F Max (V) $T_A = +25^\circ\text{C}$	I_R Max (mA) $T_A = +25^\circ\text{C}$
50/60	1.0	0.7	0.5

Description and Applications

This Schottky Barrier Rectifier is designed to meet the general requirements of commercial applications. It is ideally suited for use as:

- Polarity Protection Diode
- Re-Circulating Diode
- Switching Diode
- Blocking Diode
- Freewheel Diode

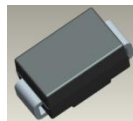
Features and Benefits

- Guard Ring Die Construction for Transient Protection
- Ideally Suited for Automated Assembly
- Low Power Loss, High Efficiency
- Surge Overload Rating to 30A Peak
- For Use in Low-Voltage, High-Frequency Inverters
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

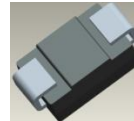
Mechanical Data

- Case: SMA & SMB
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Lead Free Plating (Matte Tin Finish). Solderable per MIL-STD-202, Method 208 ③
- Polarity: Cathode Band or Cathode Notch
- Weight:
 - SMA 0.064 grams (Approximate)
 - SMB 0.093 grams (Approximate)

Green



Top View



Bottom View

Ordering Information (Note 5)

Part Number	Qualification	Case	Packaging
B1X0Q-13-F	Automotive	SMA	5,000/Tape & Reel
B1X0BQ-13-F	Automotive	SMB	3,000/Tape & Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to <https://www.diodes.com/quality/>.
 5. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

B120Q/BQ - B160Q/BQ

1.0A SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Characteristic	Symbol	B120Q/BQ	B130Q/BQ	B140Q/BQ	B150Q/BQ	B160Q/BQ	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	20	30	40	50	60	V
Working Peak Reverse Voltage	V _{RWM}						
DC Blocking Voltage	V _R						
RMS Reverse Voltage	V _{R(RMS)}	14	21	28	35	42	V
Average Rectified Output Current @ T _T = +130°C	I _O	1.0					A
Non-Repetitive Peak Forward Surge Current 8.3ms	I _{FSM}	30					A
Single Half Sine-Wave Superimposed on Rated Load							
Electrostatic Discharge	HBM	4000					V
Electrostatic Discharge	MM	400					V
Electrostatic Discharge	CDM	1					kV

Thermal Characteristics

Characteristic	Symbol	B120Q/BQ	B130Q/BQ	B140Q/BQ	B150Q/BQ	B160Q/BQ	Unit
Typical Thermal Resistance Junction to Ambient (Note 6)	R _{θJA}	115					°C/W
Typical Thermal Resistance Junction to Ambient (Note 7)	R _{θJA}	65					°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150					°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Forward Voltage Drop B120Q/BQ, B130Q/BQ, B140Q/BQ B150Q/BQ, B160Q/BQ	V _F	—	—	0.5 0.7	V	I _F = 1.0A I _F = 1.0A
Leakage Current (Note 8)	I _R	—	—	0.5 10	mA	@ Rated V _R , T _A = +25°C @ Rated V _R , T _A = +100°C
Total Capacitance	C _T	—	—	110	pF	V _R = 4V, f = 1MHz
Switching Speed	t _{RR}	—	12	—	ns	I _F = 0.5A, I _R = 1A, I _{RR} = 0.25A (RG1)

- Notes:
- 1*MRP FR-4 PC board, 2oz.
 7. With 50mm*50mm*23mm Al heatsink.
 8. Short duration pulse test used to minimize self-heating effect.

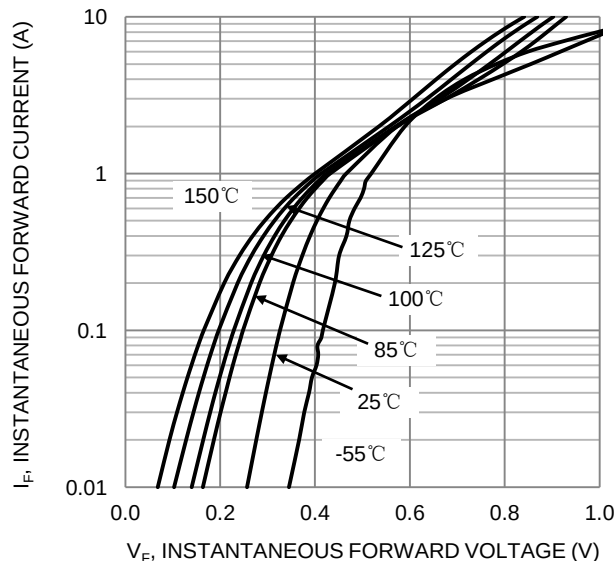


Figure 1. Typical Forward Characteristics
B120Q/BQ-B140Q/BQ

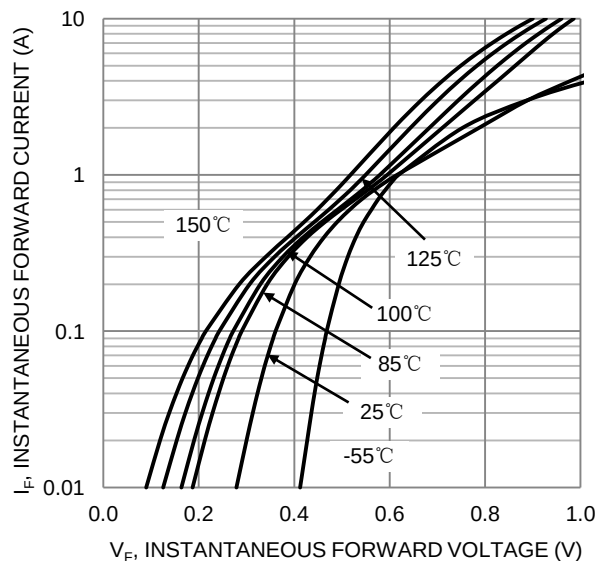


Figure 2. Typical Forward Characteristics
B150Q/BQ - B160Q/BQ

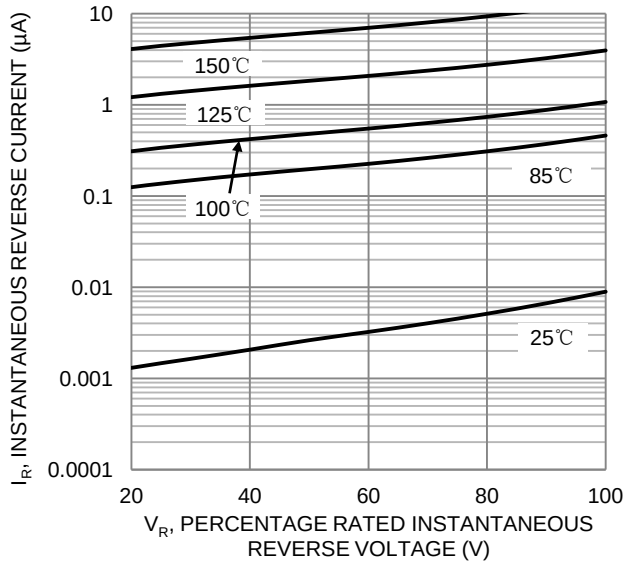


Figure 3. Typical Reverse Characteristics
B120Q/BQ - B140Q/BQ

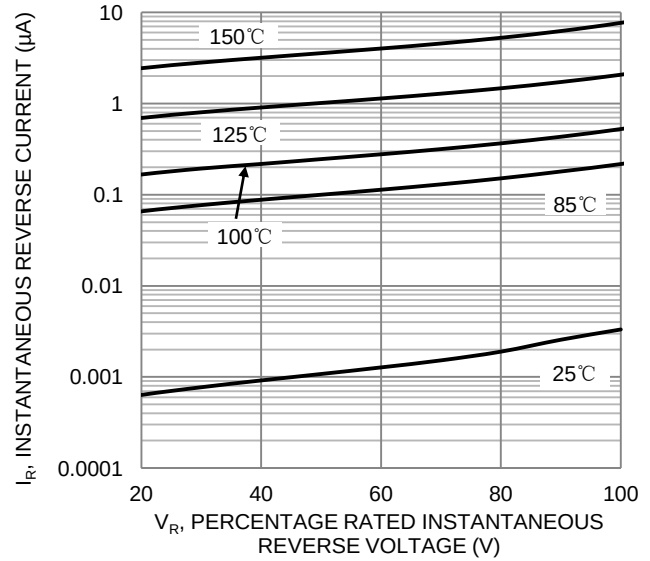


Figure 4. Typical Reverse Characteristics
B150Q/BQ - B160Q/BQ

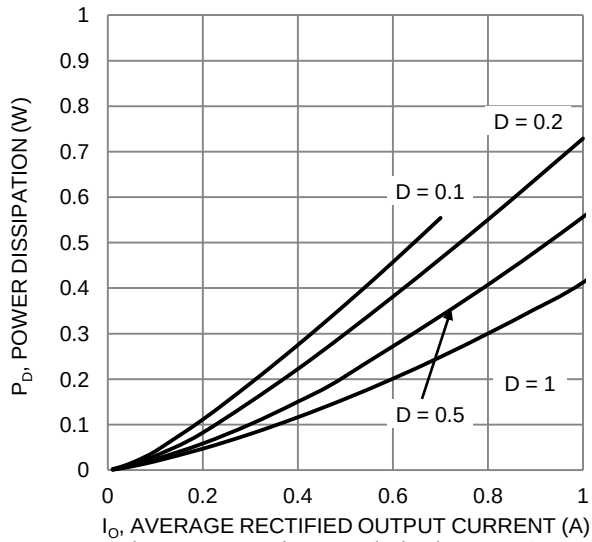


Figure 5. Forward Power Dissipation $T_J = 125^\circ\text{C}$
B120Q/BQ - B140Q/BQ

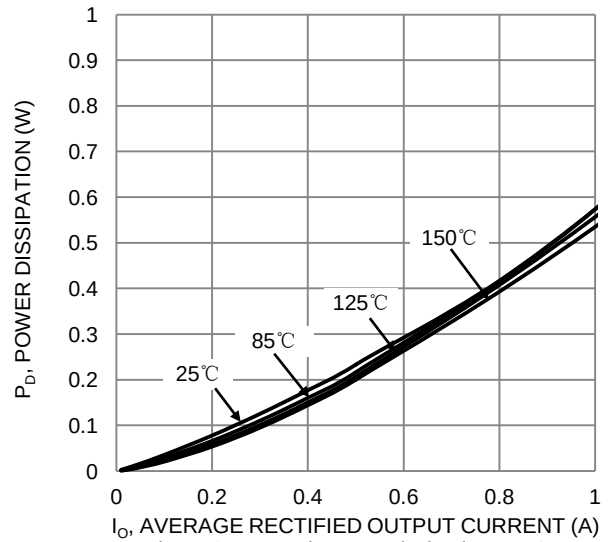


Figure 6. Forward Power Dissipation $D = 0.5$
B120Q/BQ - B140Q/BQ

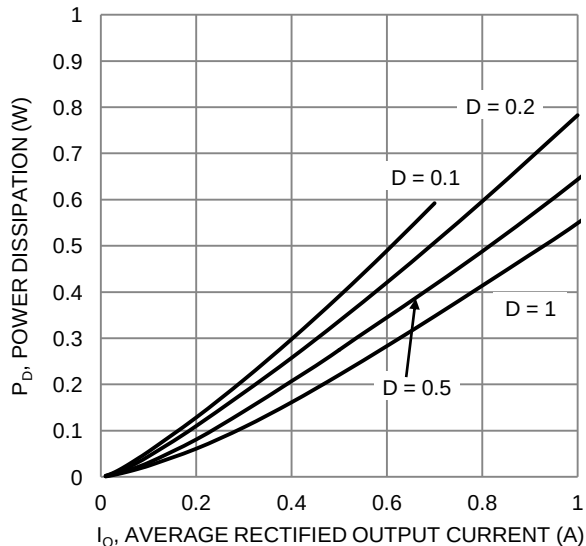


Figure 7. Forward Power Dissipation $T_J = 125^\circ\text{C}$
B150Q/BQ - B160Q/BQ

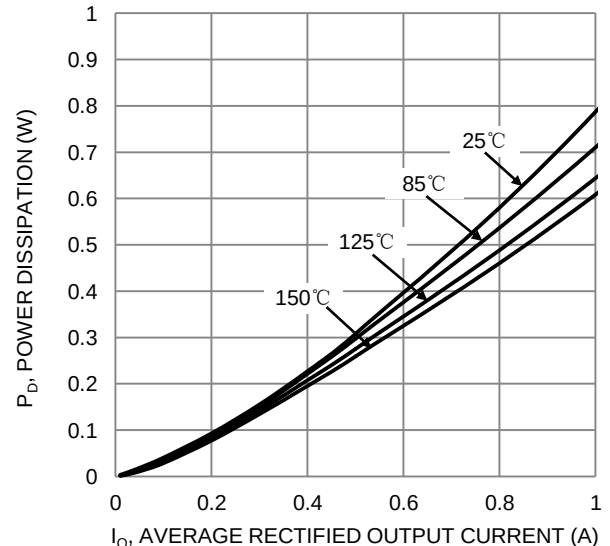
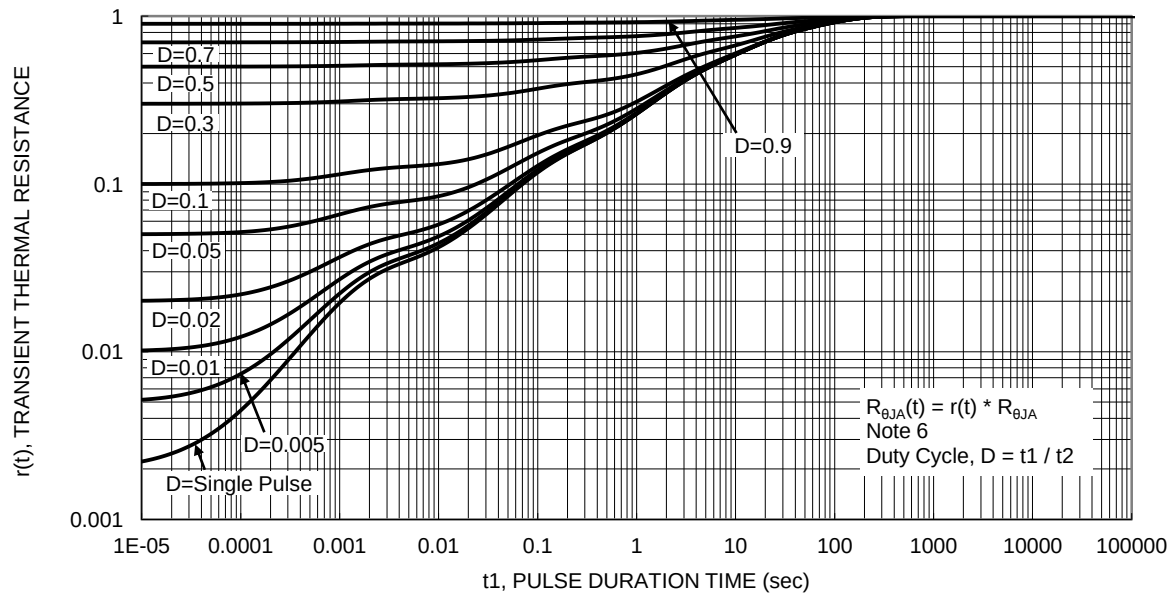
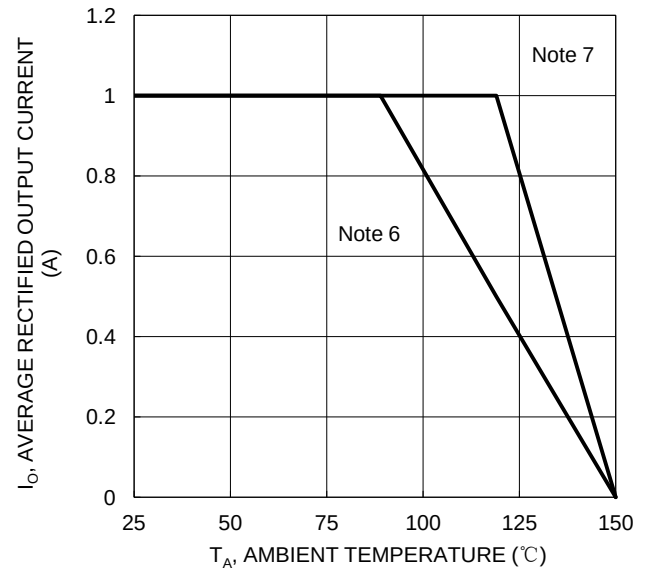
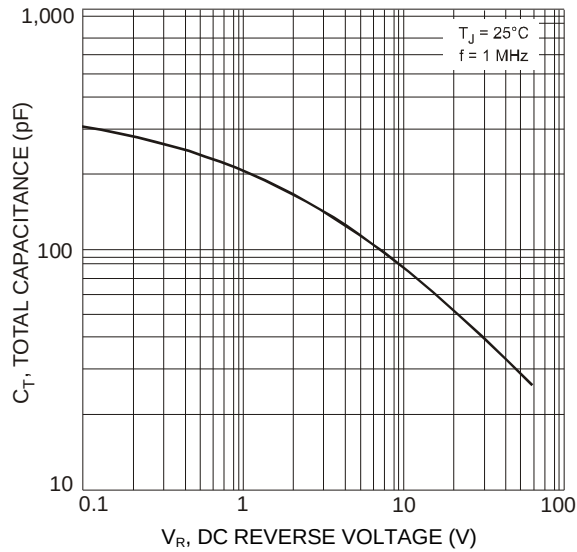
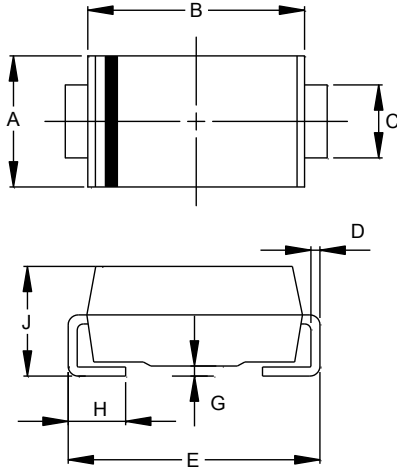


Figure 8. Forward Power Dissipation $D = 0.5$
B150Q/BQ - B160Q/BQ



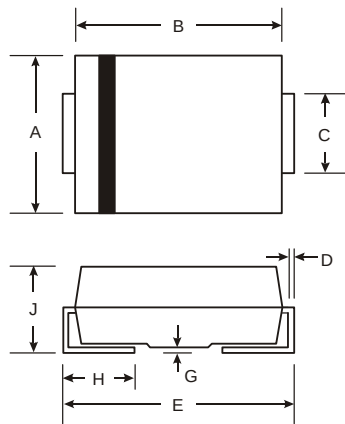
Package Outline Dimensions

SMA



SMA		
Dim	Min	Max
A	2.29	2.92
B	4.00	4.60
C	1.27	1.63
D	0.15	0.31
E	4.80	5.59
G	0.05	0.20
H	0.76	1.52
J	1.96	2.40
All Dimensions in mm		

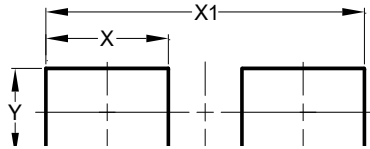
SMB



SMB		
Dim	Min	Max
A	3.30	3.94
B	4.06	4.57
C	1.96	2.21
D	0.15	0.31
E	5.00	5.59
G	0.05	0.20
H	0.76	1.52
J	2.00	2.50
All Dimensions in mm		

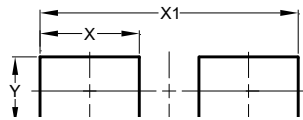
Suggested Pad Layout

SMA



Dimensions	Value (in mm)
C	4.00
G	1.50
X	2.50
X1	6.50
Y	1.70

SMB



Dimensions	Value (in mm)
C	4.30
G	1.80
X	2.50
X1	6.80
Y	2.30